Solid State GaN Power Amplifiers

- L-Band
- S-Band
- C-Band
- X-Band
GaN Amplifiers provide high gain, high efficiency and excellent stability, with excellent AM/PM and phase-noise performance

L-Band Solid State Power Amplifiers

Military Long Range Search Radars
VSL3606 L-Band GaN High Power SSPA
• Frequency range: 1.2 – 1.4 GHz
• 700 Watt modules with ALC (Automatic leveling control)
• Excellent pulse fidelity for radar applications

1.3 kW to 20 kW Amplifiers are available by power combining modules if high power is needed with a single output.

BIT and controls via EIA-422 for remote control and diagnostics.

For use in Particle Accelerators
VSL3616 L-Band GaN - CW, High Power SSPA
• Frequency range: 1.3 GHz
• 700 W CW
• Liquid cooled
• 700 W units can be power-combined using external power combiners if desired for higher power
• Optimized for scientific applications

Excellent AM/PM and phase noise performance for use in particle accelerators.
GaN Amplifiers provide high gain, high efficiency and excellent stability, with excellent AM/PM and phase-noise performance

**S-Band Solid State GaN Power Amplifiers**

- Frequency range: 2.7 to 2.9 GHz
- BIT and controls via EIA-422 remote connection
- 1.3 kW pulsed modules
- Built-in VSWR protection
- Compliant to NTIA regulatory requirements

- Provide high gain, excellent pulse fidelity
- Excellent pulse fidelity with low AM/PM, phase-noise and spectral regrowth performance
- Easy to maintain

**For use in Air Traffic Control radar systems**

**VSS3617 S-Band GaN High Power Transmitters**
- Transmitter cabinet with 12 kW minimum peak output power
- Soft fail by virtue of power combining
- Full redundancy
- >160 dB of power attenuation available
- Designed for ATC shelter applications

**VSS3607 S-Band GaN High Power SSPA**
- 1.3 kW pulsed modules that can be power combined for higher peak power output
- Internal processor with BITE monitoring
- Self protecting

**Military Precision Approach Radar Transmitters**

**VSS3635 S-Band GaN High Power Transmitters**
- Transmitter with 10 kW minimum peak power output.
- Soft fail by virtue of power combining
- Excellent noise performance due to operation off of stored energy during the RF pulse
- Designed for small mobile applications

**VSS3607 S-Band GaN High Power SSPA**
- 1.3 kW pulsed modules that can be power combined for higher peak power output
- Internal BIT circuitry via EIA-422 remote connection
- Self protecting
The values listed above represent specified limits for the product and are subject to change. The data should be used for basic information only. Formal, controlled specifications may be obtained from CPI for use in equipment design.

For information on this and other CPI products visit our web page at www.cpii.com/bmd, or contact:
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